

Data sheet acquired from Harris Semiconductor SCHS261

January 1997

NOT RECOMMENDED FOR NEW DESIGNS Use CMOS Technology

BiCMOS FCT Interface Logic, Octal Bus Transceiver/Register, Three-State

Features

- · Buffered Inputs
- Typical Propagation Delay: 6.8ns at $V_{CC} = 5V$, $T_A = 25^{\circ}C$, $C_L = 50pF$
- Noninverting
- SCR Latchup Resistant BiCMOS Process and Circuit Design
- Speed of Bipolar FAST™/AS/S
- 64mA Output Sink Current
- Output Voltage Swing Limited to 3.7V at V_{CC} = 5V
- Controlled Output Edge Rates
- Input/Output Isolation to V_{CC}
- . BiCMOS Technology with Low Quiescent Power

Ordering Information

PART NUMBER	TEMP. RANGE (^O C)	PACKAGE	PKG. NO.
CD74FCT646EN	0 to 70	24 Ld PDIP	E24.3
CD74FCT646M	0 to 70	24 Ld SOIC	M24.3
CD74FCT646SM	0 to 70	24 Ld SSOP	M24.209

NOTE: When ordering the suffix M and SM packages, use the entire part number. Add the suffix 96 to obtain the variant in the tape and reel.

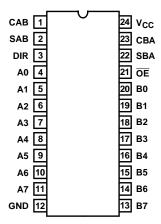
Description

The CD74FCT646 three-state octal bus transceiver/register uses a small geometry BiCMOS technology. The output stage is a combination of bipolar and CMOS transistors that limits the output HIGH level to two diode drops below V_{CC} . This resultant lowering of output swing (0V to 3.7V) reduces power bus ringing (a source of EMI) and minimizes V_{CC} bounce and ground bounce and their effects during simultaneous output switching. The output configuration also enhances switching speed and is capable of sinking 64 milliamperes.

This device is a bus transceiver with D-Type flip-flops which act as internal storage registers on the LOW to HIGH transition of either CAB or CBA clock inputs. Output Enable (\overline{OE}) and Direction (DIR) inputs control the transceiver functions. Data present at the high impedance output can be stored in either register or both but only one of the two buses can be enabled as outputs at any one time. The Select controls (SAB and SBA) can multiplex stored and transparent (real time) data. The Direction control determines which data bus will receive data when the Output Enable (\overline{OE}) is LOW. In the high impedance mode (Output Enable HIGH), A data can be stored in one register and B data can be stored in the other register. The clocks are not gated with the Direction (DIR) and Output Enable (\overline{OE}) terminals; data at the A or B terminals can be clocked into the storage flip-flops at any time.

Pinout

CD74FCT646 (PDIP, SOIC, SSOP) TOP VIEW



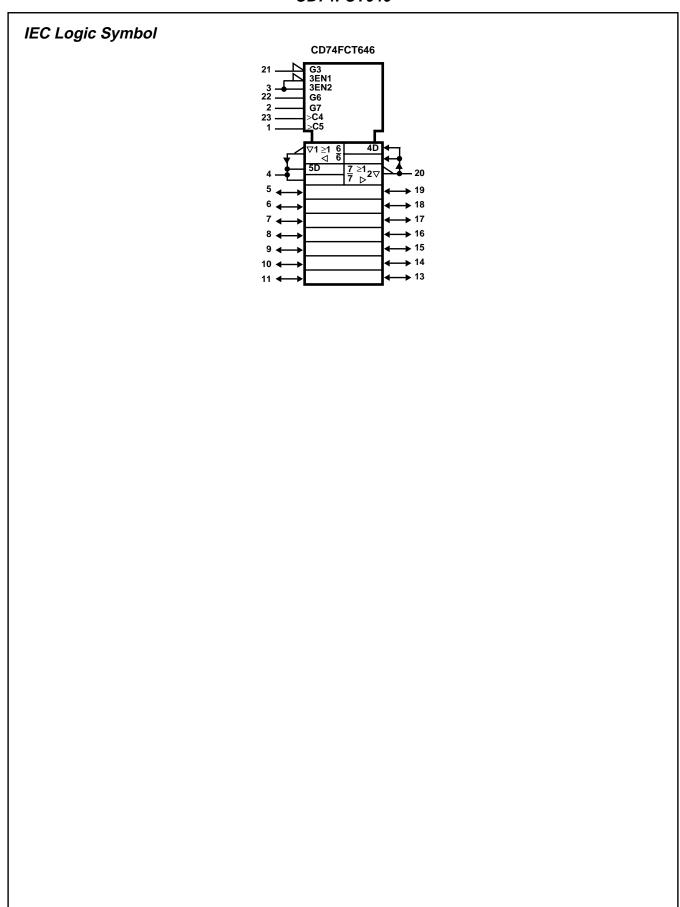
Functional Diagram ADATA PORT ADATA SOURCE SELECTION INPUTS GND = PIN 12 VCC = PIN 24

TRUTH TABLE (Note 1)

		INP	UTS			DATA I/O	O (Note 2)	OPERATION OR FUNCTION		
OE	DIR	CAB	CBA	SAB	SBA	A0 THRU A7	B0 THRU B7	CD74FCT646		
X	X X	↑ X	X ↑	X X	X X	Input Not Specified	Not Specified Input	Store A, B Unspecified Store B, A Unspecified		
H H	X X	↑ H or L	↑ H or L	X X	X X	Input	Input	Store A and B Data Isolation, Hold Storage		
L L	L L	X X	X H or L	X X	L H	Output	Input	Real Time B Data to A Bus Stored B Data to A Bus		
L L	H H	X H or L	X X	L H	X X	Input	Output	Real Time A Data to B Bus Stored A Data to B Bus		

NOTES:

- 1. H= HIGH Voltage Level
 - L = LOW Voltage Level
 - ↑ = Transition from Low to High
 - X = Immaterial
- The data output functions may be enabled or disabled by various signals at the OE and DIR inputs. Data input functions are always enabled, i.e., data at the bus pins will be stored on every low to high transition of the clock inputs. To prevent excess currents in the high Z modes, all I/O terminals should be terminated with 10kΩ resistors.



Thermal Information Absolute Maximum Ratings DC Supply Voltage (VCC) -0.5V to 6V Thermal Resistance (Typical, Note 3) θ_{JA} (oC/W) DC Diode Current, I_{IK} (For $V_I < -0.5V$)....-20mA DC Output Diode Current, I_{OK} (for $V_O < -0.5V$) -50mA DC Output Source Current per Output Pin, IO -30mA Maximum Storage Temperature Range-65°C to 150°C DC Ground Current (I_{GND})......528mA Maximum Lead Temperature (Soldering 10s).....300°C (SOIC and SSOP-Lead Tips Only) **Operating Conditions**

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

3. θ_{JA} is measured with the component mounted on an evaluation PC board in free air.

Electrical Specifications Commercial Temperature Range 0°C to 70°C, V_{CC} Max = 5.25V, V_{CC} Min = 4.75V (Note 6)

					AMBIENT TEMPERATURE (T _A)				
		TEST CONDITIONS			25°C		0°C TO 70°C		1
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	V _{CC} (V)	MIN	MAX	MIN	MAX	UNITS
High Level Input Voltage	V _{IH}			4.75 to 5.25	2	-	2	-	V
Low Level Input Voltage	V _{IL}			4.75 to 5.25	-	0.8	-	0.8	V
High Level Output Voltage	V _{OH}	V _{IH} or V _{IL}	-15	Min	2.4	-	2.4	-	V
Low Level Output Voltage	V _{OL}	V _{IH} or V _{IL}	64	Min	-	0.55	-	0.55	V
High Level Input Current	I _{IH}	Vcc		Max	-	0.1	-	1	μΑ
Low Level Input Current	I _{IL}	GND		Max	-	-0.1	-	-1	μΑ
Three-State Leakage Current	lozh	Vcc		Max	-	0.5	-	10	μΑ
	I _{OZL}	GND		Max	-	-0.5	-	-10	μΑ
Input Clamp Voltage	V _{IK}	V _{CC} or GND	-18	Min	-	-1.2	-	-1.2	V
Short Circuit Output Current (Note 4)	I _{OS}	V _O = 0 V _{CC} or GND		Max	-60	-	-60	-	mA
Quiescent Supply Current, MSI	Icc	V _{CC} or GND	0	Max	-	8	-	80	μΑ
Additional Quiescent Supply Current per Input Pin TTL Inputs High, 1 Unit Load	Δl _{CC}	3.4V (Note 5)		Max	-	1.6	-	1.6	mA

NOTES:

- 4. Not more than one output should be shorted at one time. Test duration should not exceed 100ms.
- 5. Inputs that are not measured are at V_{CC} or GND.
- 6. FCT Input Loading: All inputs are 1 unit load. Unit load is ΔI_{CC} limit specified in Electrical Specifications table, e.g., 1.6mA Max. at 70°C.

Switching Specifications Over Operating Range FCT Series t_r , $t_f = 2.5$ ns, $C_L = 50$ pF, R_L (Figure 1) (Note 7)

			25°C	0°C T	O 70°C	
PARAMETER	SYMBOL	V _{CC} (V)	TYP	MIN	MAX	UNITS
Propagation Delays		(Note 8)				
Store An \rightarrow Bn, Store Bn \rightarrow An, An \rightarrow Bn, Bn \rightarrow An	t _{PLH} , t _{PHL}	5	6.8	2	9	ns
Select to Data	t _{PLH} , t _{PHL}	5	8.3	2	11	ns
Output Enable to Output	t _{PZL} , t _{PZH}	5	10.5	2	14	ns
Output Disable to Output	t _{PLZ} , t _{PHZ}	5	6.8	2	9	ns
Power Dissipation Capacitance	C _{PD} (Note 8)	-	-	-	-	pF
Minimum (Valley) V _{OHV} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OHV}	5	0.5	-	-	V
Maximum (Peak) V _{OLP} During Switching of Other Outputs (Output Under Test Not Switching)	V _{OLP}	5	1	-	-	V
Input Capacitance	C _I	-	-	-	10	pF
Input/Output Capacitance	C _{I/O}	-	-	-	15	pF

NOTES:

- 7. 5V: Minimum is at 5.25V for 0°C to 70°C, Maximum is at 4.75V for 0°C to 70°C, Typical is at 5V.
- 8. C_{PD}, measured per flip-flop, is used to determine the dynamic power consumption.

P_D (per package) = $V_{CC}I_{CC} + \Sigma(V_{CC}^2 f_I C_{PD} + V_O^2 f_O C_L + V_{CC} \Delta I_{CC} D)$ where: V_{CC} = supply voltage

 ΔI_{CC} = flow through current x unit load C_L = output load capacitance

D = duty cycle of input high f_O = output frequency

f_I = input frequency

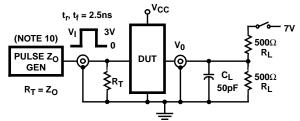
Prerequisite For Switching

			25 ⁰ C	0°C TO 70°C		
PARAMETER	SYMBOL	V _{CC} (V)	TYP	MIN	MAX	UNITS
Maximum Frequency	f _{MAX}	5 (Note 9)	-	85	-	ns
Data to Clock Setup Time	tsu	5	-	4	-	ns
Data to Clock Hold Time	t _H	5	-	2	-	ns
Clock Pulse Width	t _W	5	-	6	-	ns

NOTE:

9. 5V: Minimum is at 4.75V for 0°C to 70°C, Typical is at 5V.

Test Circuits and Waveforms



NOTE:

10. Pulse Generator for All Pulses: Rate \leq 1.0MHz; $Z_{OUT} \leq$ 50 Ω ; $t_f, t_r \leq$ 2.5ns.

FIGURE 1. TEST CIRCUIT

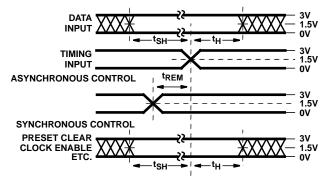


FIGURE 2. SETUP, HOLD, AND RELEASE TIMING

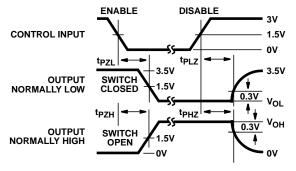


FIGURE 4. ENABLE AND DISABLE TIMING

SWITCH POSITION

TEST	SWITCH			
t _{PLZ} , t _{PZL} , Open Drain	Closed			
t _{PHZ} , t _{PZH} , t _{PLH} , t _{PHL}	Open			

DEFINITIONS:

C_L = Load capacitance, includes jig and probe capacitance.

 R_T = Termination resistance, should be equal to $Z_{\mbox{OUT}}$ of the Pulse Generator.

 $V_{IN} = 0V$ to 3V.

Input: $t_r = t_f = 2.5$ ns (10% to 90%), unless otherwise specified

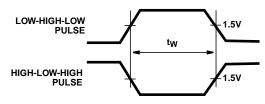


FIGURE 3. PULSE WIDTH

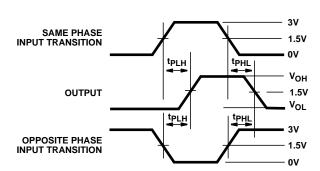
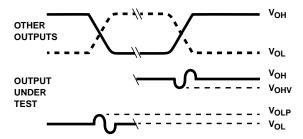


FIGURE 5. PROPAGATION DELAY

Test Circuits and Waveforms (Continued)



NOTES:

- 11. V_{OLP} is measured with respect to a ground reference near the output under test. V_{OHV} is measured with respect to V_{OH} .
- 12. Input pulses have the following characteristics: $P_{RR} \leq 1 \\ \text{MHz}, \ t_f = 2.5 \\ \text{ns}, \ t_f = 2.5 \\ \text{ns}, \ \text{skew 1ns}.$
- 13. R.F. fixture with 700MHz design rules required. IC should be soldered into test board and bypassed with $0.1\mu F$ capacitor. Scope and probes require 700MHz bandwidth.

FIGURE 6. SIMULTANEOUS SWITCHING TRANSIENT WAVEFORMS

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